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PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/826,661	04/05/2001	Yongjun Hu	303.098US4	4539
21186	7590 12/11/2003		EXAMINER	
SCHWEGM	1AN, LUNDBERG, WO	NGUYEN, JOSEPH H		
P.O. BOX 29	38 LIS, MN 55402		ART UNIT	PAPER NUMBER
WINNEAT OLIS, WIN 33402		2815		

DATE MAILED: 12/11/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

			<u> </u>				
)	Application No.	Applicant(s)				
055		09/826,661	HU, YONGJUN				
Office Action Summa	iry	Examiner	Art Unit				
		Joseph Nguyen	2815				
The MAILING DATE of this co Period for Reply	mmunication appea	ars on the cover sheet with the c	orrespondence address				
A SHORTENED STATUTORY PER THE MAILING DATE OF THIS COM - Extensions of time may be available under the pafter SIX (6) MONTHS from the mailing date of in the period for reply specified above is less that if NO period for reply is specified above, the material period in the set or extended period in the set of extended period in the se	MMUNICATION. rovisions of 37 CFR 1.136(his communication. n thirty (30) days, a reply w kimum statutory period will for reply will, by statute, ca months after the mailing da	(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) days apply and will expire SIX (6) MONTHS from ause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
1) Responsive to communication	n(s) filed on <u>06 Oct</u>	ober 2003.					
2a) ☐ This action is FINAL.	2b)⊠ This ac	ction is non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims			• .				
4) Claim(s) 48-54,71-73,75,76,8	<u>2-89,91-100,102,1</u>	03 and 105-116 is/are pending	in the application.				
4a) Of the above claim(s)	4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) <u>48-54,82-89,91-97</u> a	Claim(s) <u>48-54,82-89,91-97 and 106-116</u> is/are allowed.						
• • • • • • • • • • • • • • • • • • • •	☑ Claim(s) <u>71-73,75,76,98-100,102,103 and 105</u> is/are rejected.						
,	,						
8) Claim(s) are subject to	restriction and/or	election requirement.					
Application Papers							
9)☐ The specification is objected to by the Examiner.							
	☑ The drawing(s) filed on <u>05 April 2001</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.						
• • • • • • • • • • • • • • • • • • • •	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
		n is required if the drawing(s) is ob					
11) The oath or declaration is objective.		miner. Note the attached Office	Action of form P1O-152.				
Priority under 35 U.S.C. §§ 119 and 1							
3. Copies of the certified application from the Int * See the attached detailed Offic 13) Acknowledgment is made of a since a specific reference was a 37 CFR 1.78.	ne of: priority documents priority documents copies of the priorit ernational Bureau ee action for a list of claim for domestic ncluded in the first eign language provi	have been received. have been received in Application of the certified copies not received priority under 35 U.S.C. § 1190 sentence of the specification of the certified application has been received priority under 35 U.S.C. § 1200 isional application has been received priority under 35 U.S.C. §§ 1200 priority under 35 U.S.C. §§	ion No ed in this National Stage ed. e) (to a provisional application) r in an Application Data Sheet. ceived. and/or 121 since a specific				
1) Notice of References Cited (PTO-892)			(PTO-413) Paper No(s)				
Notice of Draftsperson's Patent Drawing R Information Disclosure Statement(s) (PTO			Patent Application (PTO-152)				

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DETAILED ACTION

In view of the appeal brief filed on 10/06/2003, PROSECUTION IS HEREBY REOPENED. A new ground of rejection is set forth below.

To avoid abandonment of the application, appellant must exercise one of the following two options:

- (1) file a reply under 37 CFR 1.111 (if this Office action is non-final) or a reply under 37 CFR 1.113 (if this Office action is final); or,
 - (2) request reinstatement of the appeal.

If reinstatement of the appeal is requested, such request must be accompanied by a supplemental appeal brief, but no new amendments, affidavits (37 CFR 1.130, 1.131 or 1.132) or other evidence are permitted. See 37 CFR 1.193(b)(2).

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 71-76 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

Claim 71 recites the limitation "the substrate" in 2. There is insufficient antecedent basis for this limitation in the claim.

Claims 72-76 are also rejected due to their dependency upon the rejected base claim 71 above.

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Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

Claims 71-73, 75-76, 98-100, 102-103, 105 are rejected under 35 U.S.C. 102(e) as being anticipated by Chen.

Regarding claim 71, Chen discloses on figure 3B in a semiconductor device, a contact hole 35 in a layer of insulator material 33 directly overlying on the substrate 31, the hole comprising a bottom surface having at least one generally planar layer of conductive material including a silicide of refractory metal 36; a substrate 31 having a profile that does not change significantly in the vicinity of the contact hole 35; and a vertical sidewall consisting substantially entirely of the aforementioned layer of insulator material 33.

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Regarding claim 72, Chen discloses on figure 3B the planar layer contacts the lower end of the sidewall.

Regarding claim 73, Chen discloses on figure 3B the planar layer does not extend substantially up the sidewall from the bottom surface.

Regarding claim 75, Chen discloses on figure 3B the planar is titanium silicide.

Regarding claim 76, Chen discloses the refractory metal is colbalt (col. 4, lines 30-31).

Regarding claim 98, Chen discloses on figure 3B an integrated circuit comprising a substrate 31; a layer of insulating material 33 overlying the substrate and containing at least one contact hole 35 having only that layer as a sidewall and having a bottom surface contacting the substrate; and at least one generally planar layer of a silicide of a refractory metal 36 where the profile of the substrate does not change substantially in the vicinity of the contact hole.

Regarding claim 99, Chen discloses on figure 3B the planar layer 36 contacts the lower end of the sidewall.

Regarding claim 100, Chen discloses on figure 3B the planar layer 36 does not extend substantially up the sidewall from the bottom surface.

Regarding claim 102, Chen discloses on figure 3B the planar layer 36 includes a silicide of titanium.

Regarding claim 103, Chen discloses the refractory metal is cobalt (col. 4, lines 30-31).

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Regarding claim 105, Chen discloses on figure 3B the planar layer contacts the lower end of the sidewall.

Allowable Subject Matter

Claims 48-54, 82-89,91-97,106-116 are allowed.

Response to Arguments

Applicant's arguments filed on 10/06/2003 have been fully considered but they are not persuasive.

With respect to claims 71 and 98, claims 71 and 98 do not include "graded stoichiometry". Also, the claim limitation "in the vicinity" is broad and Chen shows no substrate profile change on either side of the contact hole. Lastly, the vertical sidewall of "the hole" is comprised of the edge of layer 33 in Chen.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Joseph Nguyen whose telephone number is (703) 308-1269. The examiner can normally be reached on Monday-Friday, 7:30 am- 4:30 pm

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone number for the organization where this application or proceeding is assigned is (703) 308-7382 for regular communications.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

JN December 1, 2003

GEORGE ECKERT
PRIMARY EXAMINER